








	<p>SI1426DH-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI1426DH-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 2.8A SC-70-6</p> <p>Datenblätter:  SI1426DH-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 34795 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1426DH-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 2.8A SC-70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	34795 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Verlustleistung (max)	1W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.8A (Ta)
Rds On (Max) @ Id, Vgs	75 mOhm @ 3.6A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	3nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)














































SI1426DH-T1-GE3 ist neu im Original, Suche SI1426DH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1426DH-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1426DH-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1424EDH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 4A SOT-363</p>	 <p>SI1426DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.8A SC-70-6</p>	 <p>SI1427EDH-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 2A SOT-363</p>	 <p>SI1428EDH-T1-GE3 VISHAY VISHAY SC70-6</p>
 <p>SI1426DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.8A SC70-6</p>	 <p>SI1428EDH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHANNEL 30V 4A SC70-6</p>	 <p>SI1424EDH-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 4A SOT-363</p>	 <p>SI1431DH-T1-E3 Vishay / Siliconix MOSFET P-CH 30V 1.7A SOT363</p>

heiße Teile

Mehr

 SI1413DH-T1	 SI1413EDH	 SI1413EDH-T1	 SI1413EDH-T1-E3	 SI1413EDH-T1-E3
 SI1413EDH-T1-GE3	 SI1413EDH-T1-GE3	 SI1414DH-T1-GE3	 SI1414DH-T1-GE3	 SI1416EDH-T1-GE3
 SI1416EDH-T1-GE3	 SI1417DH-T1-E3	 SI1417DH-T1-GE3	 SI1417EDH-T1	 SI1417EDH-T1-E3
 SI1417EDH-T1-E3	 SI1417EDH-T1-GE3	 SI1417EDH-T1-GE3	 SI1422DH-T1-GE3	 SI1422DH-T1-GE3
 SI1424EDH-T1-GE3	 SI1424EDH-T1-GE3	 SI1426DH-T1-E3	 SI1426DH-T1-E3	 SI1426DH-T1-GE3
 SI1427EDH-T1-GE3	 SI1427EDH-T1-GE3	 SI1428EDH-T1-GE3	 SI1428EDH-T1-GE3	 SI1433DH-T1
 SI1433DH-T1-E3	 SI1433DH-T1-E3	 SI1433DH-T1-GE3	 SI1433DH-T1-GE3	 SI1441EDH-T1-GE3
 SI1441EDH-T1-GE3	 SI1442DH-T1-GE3	 SI1442DH-T1-GE3	 SI1443EDH-T1-GE3	 SI1443EDH-T1-GE3
 SI1467DH-T1-GE3	 SI1467DH-T1-GE3	 SI1469DH-T1-GE3	 SI1469DH-T1-GE3	 SI1470DH-M6TR
 SI1470DH-T1-GE3	 SI1470DH-T1-GE3	 SI1471DH-T1	 SI1471DH-T1-E3	 SI1471DH-T1-E3

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